TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL PLANAR TYPE (PCT PROCESS)

2 S C 4 5 3 9

POWER AMPLIFIER APPLICATIONS

POWER SWITCHING APPLICATIONS

• Low Saturation Voltage : $V_{CE (sat)} = 0.5V$ (Max.)

 $(I_C = 700 \text{mA})$

• High Speed Switching Time : $t_{stg} = 0.3 \mu s$ (Typ.)

• Small Flat Package

• P_C=1~2W (Mounted on Ceramic Substrate)

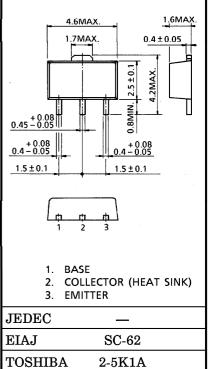
• Complementary to 2SA1734

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	v_{CBO}	50	V
Collector-Emitter Voltage	V_{CEO}	30	V
Emitter-Base Voltage	$V_{ m EBO}$	6	V
Collector Current	$_{ m IC}$	1.2	A
Base Current	$I_{\mathbf{B}}$	0.3	Α
Collector Power Dissipation	$P_{\mathbf{C}}$	500	mW
Collector Power Dissipation	Pc (Note)	1000	mW
Junction Temperature	T_{j}	150	°C
Storage Temperature Range	$\mathrm{T}_{\mathrm{stg}}$	-55~150	°C

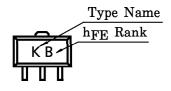
(Note): Mounted on ceramic substrate $(250 mm^2 \times 0.4t)$

Unit in mm



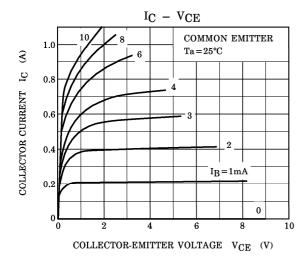
Weight: 0.05g

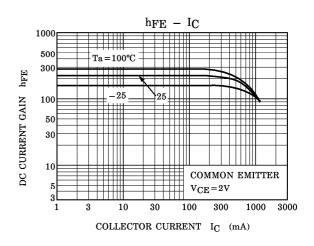
MARKING

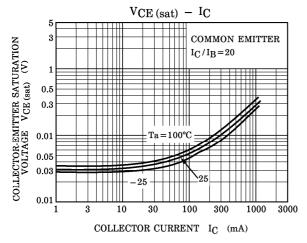


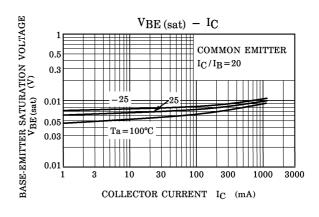
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

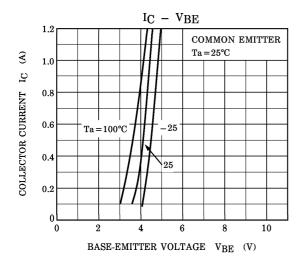
CHARAC	TERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current		ICBO	$V_{CB} = 50V, I_{E} = 0$	_	_	0.1	μ A
Emitter Cut-off Current		I_{EBO}	$V_{EB}=6V, I_{C}=0$	_	_	0.1	μ A
Collector-Emitter Breakdown Voltage			$I_{C}=10mA, I_{B}=0$	30	_	_	V
DC Current Gain		h _{FE (1)}	$V_{CE} = 2V, I_{C} = 100 mA$	120	_	400	
		h _{FE} (2)	$V_{CE} = 2V, I_{C} = 1.0A$	40	_	_	
Collector-Emitter Saturation Voltage		V _{CE} (sat)	$I_{C} = 700 \text{mA}, I_{B} = 35 \text{mA}$	_	_	0.5	V
Base-Emitter Saturation Voltage		V _{BE} (sat)	$I_{C} = 700 \text{mA}, I_{B} = 35 \text{mA}$	_	_	1.2	V
Transition Frequency		$ m f_T$	$V_{CE}=2V, I_{C}=100mA$	_	100	_	MHz
Collector Output Capacitance		C_{ob}	$V_{CB} = 10V, I_{E} = 0, f = 1MHz$	_	10	_	pF
Switching Time	Turn-on Time	t _{on}	IB1 INPUT IB2 IB2 I 14V		0.1	_	
	Storage Time	$t_{ ext{stg}}$		_	0.3	_	μ s
	Fall Time	tf	$I_{B1} = -I_{B2} = 35$ mA, DUTY CYCLE $\leq 1\%$	_	0.1	_	

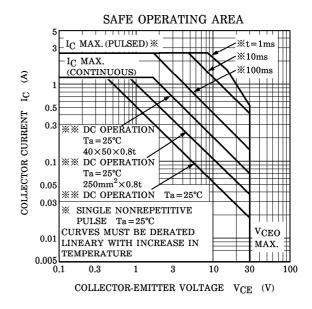


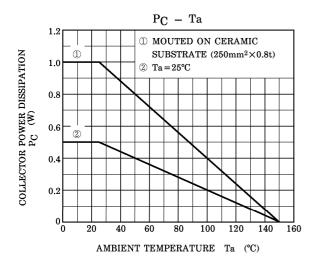












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